MAX3045BxxE Rev. A

RELIABILITY REPORT

FOR

MAX3045BxxE

PLASTIC ENCAPSULATED DEVICES

May 26, 2003

MAXIM INTEGRATED PRODUCTS

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SUNNYVALE, CA 94086

Written by

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Conclusion

The MAX3045B successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX3045B is a 5V quad RS-485/RS-422 transmitter designed for digital data transmission over twisted-pair balanced lines. The transmitter outputs are protected to ±10kV using the Human Body Model. The MAX3045B is a slew-rate limited transmitters that minimize EMI and reduce reflections caused by improperly terminated cables, thus allowing error-free transmission.

The MAX3045B features a hot-swap capability^{*} that eliminates false transitions on the data cable during power-up or hot insertion. The MAX3045B is optimized for data transfer rates up to 20Mbps.

The MAX3045B is a ESD-protected pin-compatible, low-power upgrades to the industry-standard. It is available in space-saving TSSOP, narrow SO, and wide SO packages.

B. Absolute Maximum Ratings

ltem	Rating
All voltages referenced to ground (GND).	
Supply Voltage (VCC)	+7V
Control Input Voltage (EN, EN, EN_)	-0.3V to (VCC + 0.3V)
Driver Input Voltage (T_IN)	-0.3V to (VCC + 0.3V)
Driver Output Voltage (Y_, Z_)(Driver Disabled)	-7.5V to +12.5V
Driver Output Voltage (Y_, Z_)(Driver Enabled)	-7.5V to +10V
Operating Temperature Range	
MAX3045BC_E	0°C to +70°C
MAX3045BE_E	-40°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Continuous Power Dissipation (TA = $+70^{\circ}$ C)	
16-Pin TSSOP	755mW
16-Pin NSO	696mW
16-Pin WSO	762mW
Derates above +70°C	
16-Pin TSSOP	9.40mW/°C
16-Pin NSO	8.70mW/°C
16-Pin WSO	9.52mW/°C

II. Manufacturing Information

A. Description/Function: ±10kV ESD-Protected, Quad 5V RS-485/RS-422 Transmitter

B. Process:	S3 (Standard 3 micron silicon gate CMOS)
C. Number of Device Transistors:	545
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Philippines, Malaysia, or Thailand
F. Date of Initial Production:	July, 2001

III. Packaging Information

A. Package Type:	16-Lead TSSOP	16-Lead NSO	16-Lead WSO
B. Lead Frame:	Copper	Copper	Copper
C. Lead Finish:	Solder Plate	Solder Plate	Solder Plate
D. Die Attach:	Silver-filled Epoxy	Silver-filled Epoxy	Silver-filled Epoxy
E. Bondwire:	Gold (1.0 mil dia.)	Gold (1.0 mil dia.)	Gold (1.0 mil dia.)
F. Mold Material:	Epoxy with silica filler	Epoxy with silica filler	Epoxy with silica filler
G. Assembly Diagram:	05-2601-0047	05-2601-0046	05-2601-0071
H. Flammability Rating:	Class UL94-V0	Class UL94-V0	Class UL94-V0

IV. Die Information

A. Dimensions:	91 x 141 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	3 microns (as drawn)
F. Minimum Metal Spacing:	3 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Jim Pedicord (Manager, Rel Operations) Bryan Preeshl (Executive Director of QA) Kenneth Huening (Vice President)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{192 \text{ x } 4389 \text{ x } 80 \text{ x } 2}$$
(Chi square value for MTTF upper limit)
Temperature Acceleration factor assuming an activation energy of 0.8eV

$$\lambda = 13.57 \times 10^{-9}$$
 $\lambda = 13.57$ F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5895) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The RT26-5 die type has been found to have all pins able to withstand a transient pulse of ± 2500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA.

Table 1 Reliability Evaluation Test Results

MAX3045BxxE

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	(Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		80	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	TSSOP NSO WSO	77 77 77	0 0 0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

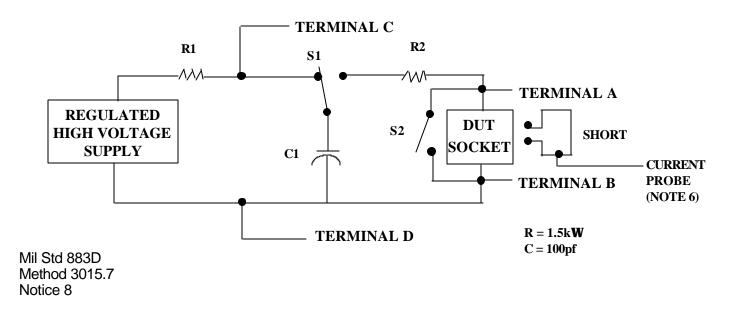
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} <u>3/</u>	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

TABLE II. Pin combination to be tested. 1/2/

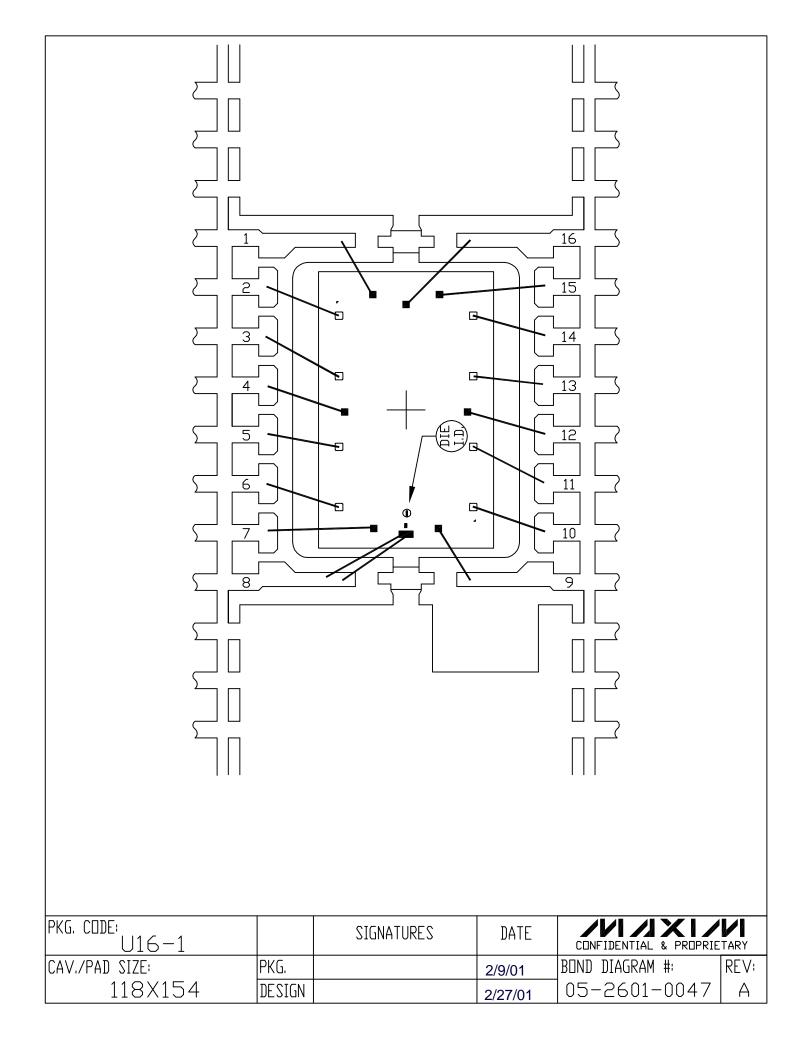
- 1/ Table II is restated in narrative form in 3.4 below.
- $\frac{\ddot{2}}{3}$ No connects are not to be tested. $\underline{3}$ Repeat pin combination I for each named Power supply and for ground

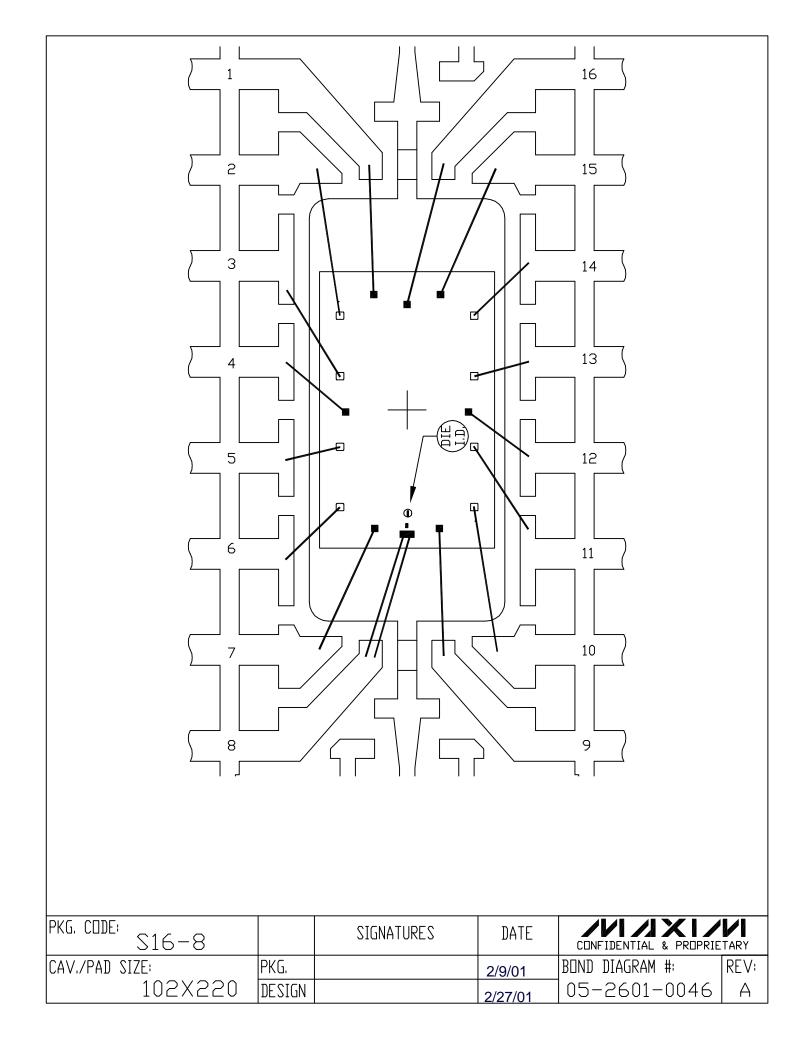
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

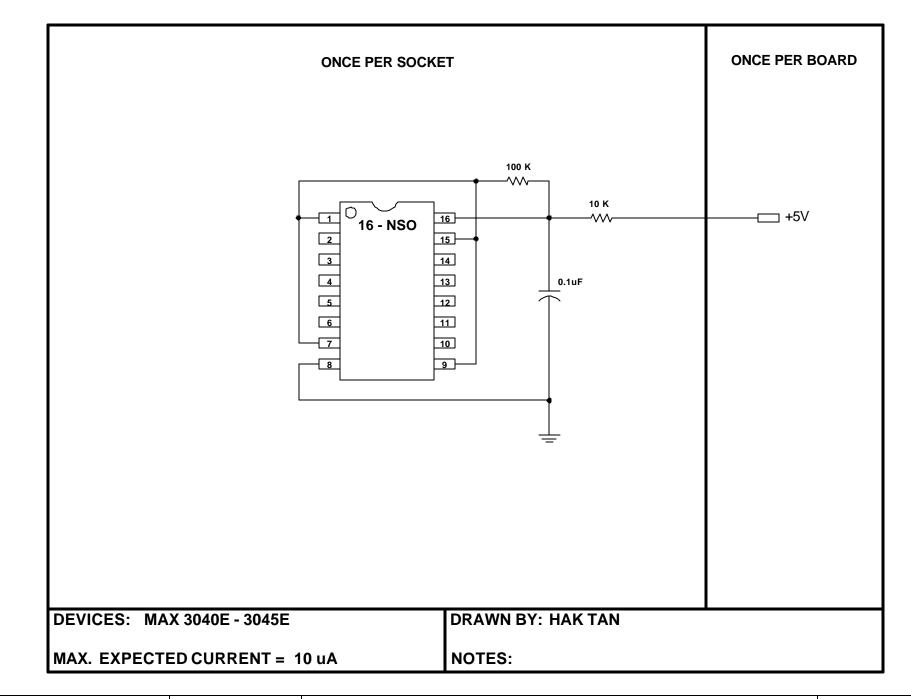
- 3.4 Pin combinations to be tested.
 - Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
 - Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
 - Each input and each output individually connected to terminal A with respect to a combination of c. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



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		G		
8			9	
PKG. CODE: W16-3	SIGNATURE	ES DATE	CONFIDENTIAL & PRO	
CAV./PAD SIZE: 160 X 200	PKG. DESIGN		BOND DIAGRAM #: 05-2601-007	REV:







DOCUMENT I.D. 06-5895